

1.6 Ω On Resistance, ± 5 V, +12 V, and +3 V Quad SPST Switches

DESCRIPTION

The DG9424E, DG9425E, DG9426E are monolithic quad single-pole-single-throw analog switches. The G9424E and DG9425E differ only in that they respond to opposite logic levels. The DG9426E has two normally open and two normally closed switches. It can be given various configurations, including four SPST, two SPDT, and one DPDT.

Using BiCMOS wafer fabrication technology allows the DG9424E, DG9425E, and DG9426E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with \pm 3 V to \pm 8 V. Each switch conducts equally well in both direction when on, and blocks input voltages up to the supply levels when off.

The low and flat on resistance over the full input signal voltage rang bring excellent linearity, reduce insertion loss and signal distortion, make them ideal for data acquisition and programmable gain control applications. These switch characters also make them ideal fit for audio signal switch and reed relay replacement.

The DG9424E, DG9425E, DG9426E feature low power dissipation, fast switching speed, and low voltage logic control threshold. Proprietary design enables the low charge injection that minimize the switching transient.

Operation temperature is specified from -40 °C to +85 °C. The DG9424E, DG9425E, DG9426E are available in 16 lead TSSOP packages.

FEATURES

- 3 V to 16 V single supply or \pm 3 V thru \pm 8 V dual supply operation
- 1.6 Ω typical on resistance
- 3 V logic compatible for control
- Bi-directional rail to rail signal switching
- Fast switching speed
- < 0.2 nA switch on leakage</p>
- Break-before-make switching DG9426

BENEFITS

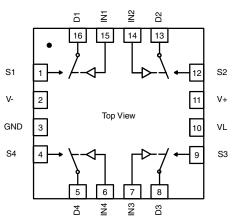
- Wide operation voltage range
- · Low signal errors and distortion
- Fast switching time
- Simple interfacing

APPLICATIONS

- · Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- · Battery powered systems
- Computer peripherals
- Audio and video signal routing

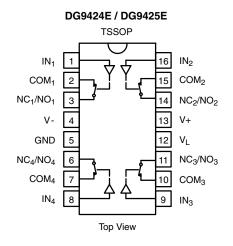
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

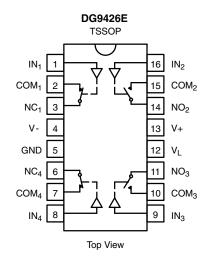
QFN-16 (4 mm x 4 mm)





FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





TRUTH TABLE						
LOGIC	DG9424E	DG9425E				
0	OFF	ON				
1	ON	OFF				

TRUTH TABLE						
LOGIC	SW ₁ , SW ₄	SW ₂ , SW ₃				
0	ON	OFF				
1	OFF	ON				

ORDERING INFORMATION								
TEMP. RANGE	PACKAGE	PART NUMBER	PART MARKING	STD PACK QUANTITY				
		DG9424EDQ-T1-GE3	9424E	Tape and reel 3000 units				
-40 °C to +85 °C	16-pin TSSOP	DG9425EDQ-T1-GE3	9425E	Tape and reel 3000 units				
-40 0 10 +65 0		DG9426EDQ-T1-GE3	9426E	Tape and reel 3000 units				
	16-pin QFN (4 mm x 4 mm)	DG9424EDN-T1-GE4	9424E	Tape and reel 2500 units				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		LIMIT	UNIT				
V+ to V-		-0.3 to +18					
GND to V-		18	V				
VL		(GND - 0.3) to (V+) + 0.3	v				
IN, COM, NC, NO ^a		(V-) - 0.3 to (V+) + 0.3					
Continuous current (NO, NC, COM pins)		100	mA				
Peak current, S or D (pulsed 1 ms, 10 % duty cycle)		200	ШA				
Storage temperature		-65 to +150	°C				
Power dissipation (package) ^b		450	mW				
Thermal resistance ^b		178	°C/W				
ESD human body model (HBM); per	ANSI / ESDA / JEDEC® JS-001	>1500	V				
Latch up current, per JESD78D		400	mA				

Notes

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board

c. Derate 7 mW/°C above 25 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

S18-0338-Rev. B, 26-Mar-18

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DG9424E, DG9425E, DG9426E

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PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 12 V, V- = 0 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f		MIN. d	TYP. °	MAX. d	
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	0	-	12	V
On-resistance	R _{ON}	V+ = 10.8 V, V- = 0 V	Room	-	1.6	3	Ω
On-resistance	TON	I_{NO} , I_{NC} = 50 mA, V_{COM} = 2/9 V	Full	-	-	4	52
Digital Control							
Input current	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-1	0.01	1	μA
Dynamic Characteristics							
Turn-on time ^e	tau		Room	-	36	51	
	t _{ON}	R_L = 300 Ω, C_L = 35 pF	Full	-	-	65	
Turn-off time ^e	V_{NO} , V_{NC} = 5 V, see fig. 2	Room	-	20	35	ns	
	t _{OFF}		Full	-	-	44	
Break-before-make time delay ^e	t _D	DG9426E only, V_{NO} , V_{NC} = 5 V R _L = 300 Ω , C _L = 35 pF		2	-	-	
Charge injection ^e	Q _{INJ}	V_g = 0 V, R_g = 0 Ω , C_L = 1 nF	Room	-	38	-	рС
Off-isolation ^e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	-	-56	-	dB
Channel-to-channel crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-77	-	uБ
NO, NC off capacitance ^e	C _{NO(off)}		Room	-	49	_	- pF
NO, NO ON Capacitance	C _{NC(off)}	f = 1 MHz	noom	-		_	
COM off capacitance ^e	C _{COM(off)}	I = I I V I I I Z	Room	-	37	-	pr
Channel on capacitance ^e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Positive supply current	l+		Room	-	0.02	1	
Positive supply current	1+		Full	-	-	5	
Negative augeby ourrept	1-		Room	-1	-0.002	-	
Negative supply current	1-		Full	-5	-	-	
Logic supply ourrent		$V_{IN} = 0 \text{ or } V_L$	Room	-	0.002	1	μA
Logic supply current	١L		Full	-	-	5	
Ground ourront			Room	-1	-0.002	-	
Ground current	I _{GND}		Full	-5	-	-	



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SPECIFICATIONS ^a Dual	Supply ± 5	V TEST CONDITIONS UNLESS			LIMITS		
PARAMETER	SYMBOL	OTHERWISE SPECIFIED	TEMP. ^b	40 °C to 195 °C			
		V+ = 5 V, V- = 5 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f		MIN. ^d	۲YP. ۵	MAX. d	
Analog Switch						<u> </u>	
Analog signal range ^e	V _{ANALOG}		Full	-5		5	V
On-resistance	R _{ON}	V+ = 4.5 V, V- = -4.5 V	Room	-	1.9	3.3	Ω
On-resistance	non	I_{NO} , $I_{NC} = 50 \text{ mA}$	Full	-	-	4.3	52
	I _{NO(off)}		Room	-1	-	1	
Switch off leakage current	I _{NC(off)}	V+ = 5.5 V, V- = -5.5 V	Full	-10	-	10	
Switch on leakage current	loour m	$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	nA
	ICOM(off)		Full	-10	-	10	
Channel on leakage current	laave s	V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	
Channel on leakage current	I _{COM(on)}	$V_{NO}, V_{NC} = V_{COM} = \pm 4.5 V$	Full	-10	-	10	
Digital Control							
Input current ^a	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-1	0.05	1	μA
Dynamic Characteristics							
Turn-on time ^e	t _{ON}	R_L = 300 Ω, C_L = 35 pF V _{NO} , V _{NC} = ± 3.5 V, see fig. 2	Room	-	48	67	ns
Turn-off time ^e	UN		Full	-	-	81	
	t _{OFF}		Room	-	34	57	
	OFF		Full	-	-	67	
Break-before-make time delay ^e	t _D	DG9426E only, V _{NO} , V _{NC} = 3.5 V R _L = 300 Ω , C _L = 35 pF	Room	2	-	-	
Charge injection ^e	Q _{INJ}	V_g = 0 V, R_g = 0 Ω , C_L = 1 nF	Room	-	112	-	рС
Off isolation ^e	OIRR	R_{L} = 50 Ω, C_{L} = 5 pF, f = 1 MHz	Room	-	-56	-	dB
Channel-to-channel crosstalk e	X _{TALK}	$M_{L} = 50.52, G_{L} = 5.6F, T = T.10Hz$	Room	-	-82	-	uБ
Source off capacitance ^e	C _{NO(off)} C _{NC(off)}		Room	-	38	-	
Drain off capacitance ^e	C _{COM(off)}	f = 1 MHz	Room	-	38	-	pF
Channel on capacitance ^e	C _{COM(on)}		Room	-	89	-	
Power Supplies	1 1			T	1	1	
Positive supply current ^e	I+		Room	-	0.03	1	
			Full	-	-	5	
Negative supply current ^e	I-	V _{IN} = 0 or V _L	Room	-1	-0.002	-	
			Full	-5	-	-	μA
Logic supply current ^e	١L		Room	-	0.002	1	μ.,
	'L		Full	-	-	5	
Ground current ^e	I _{GND}		Room	-1	-0.002	-	
	GND		Full	-5	-	-	

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SPECIFICATIONS a Single Supply 5 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, V- = 0 V V_L = 5 V, V_{IN} = 2.4 V, 0.8 V ^f		MIN. ^d	TYP. °	MAX. d	_
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	-	-	5	V
On-resistance ^e	R _{ON}	V+ = 4.5 V, I _{NO} , I _{NC} = 50 mA	Room	-	3.1	4.8	Ω
On-resistance s	PON	$v_{\pm} = 4.5 v, i_{NO}, i_{NC} = 50 \text{ mA}$	Full	-	-	5.8	52
Dynamic Characteristics							
Turn-on time ^e	+		Room	-	62	78	
runi-on time °	t _{ON}	R _L = 300 Ω, C _L = 35 pF	Hot	-	-	106	
Turn-off time ^e	t _{OFF}	V_{NO} , V_{NC} = 3.5 V, see fig. 2	Room	-	29	44	ns
			Hot	-	-	56	
Break-before-make time delay ^e	t _D	DG9426E only, V _{NO} , V _{NC} = 3.5 V R _L = 300 $\Omega,$ C _L = 35 pF	Room	5	-	-	
Charge injection ^e	Q _{INJ}	$V_g = 0 V, R_g = 0 \Omega, C_L = 1 nF$	Room	-	10	-	рС
Power Supplies			•				
			Room	-	0.02	1	
Positive supply current ^e	l+	I+	Hot	-	-	5	
Negotive cupply current f	I-		Room	-1	-0.002	-	
Negative supply current ^e	1-		Hot	-5	-	-	
		$V_{IN} = 0$ or V_L	Room	-	0.002	1	μA
Logic supply current ^e	١L		Hot	-	-	5	
Ground current ^e	1		Room	-1	-0.002	-	
Ground current *	I _{GND}		Hot	-5	-	-	



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SPECIFICATIONS ^a Singl	le Supply 3	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
	••••••	V+ = 3 V, V- = 0 V V _L = 3 V, V _{IN} = 2.4 V, 0.4 V ^f		MIN. d	TYP. °	MAX. d	•••••
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	0	-	3	V
On-resistance	R _{ON}	V+ = 2.7 V, V- = 0 V	Room	-	6	-	Ω
On-resistance	TON	I_{NO} , I_{NC} = 5 mA, V_{COM} = 0.5, 2.2 V	Full	-	-	-	52
	I _{NO(off)}		Room	-1	-	1	
Switch off leakage current ^a	I _{NC(off)}	V+ = 3.3 V, V- = 0 V	Full	-10	-	10	
Switch on leakage current	V _{COM} = 0.3, 3 V, V _{NO} , V _{NC} = 3, 0.3 V	$V_{COM} = 0.3, 3 V, V_{NO}, V_{NC} = 3, 0.3 V$	Room	-1	-	1	n۸
	I _{COM(off)}		Full	-10	-	10	nA
Channel on leakage current ^a		V+ = 3.3 V, V- = 0 V,	Room	-1	-	1	-
Channel on leakage current "	I _{COM(on)}	$V_{NO}, V_{NC} = V_{COM} = 0.3, 3 V$	Full	-10	-	10	
Digital Control ^e							
Input current	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-1	0.005	1	μA
Dynamic Characteristics							
Turn-on time	t _{ON}		Room	-	140	-	
rum-on time	UN	$R_L = 300 \Omega$, $C_L = 35 pF$	Full	-	-	193	
Turn-off time	t _{OFF}	V_{NO} , V_{NC} = 1.5 V, see fig. 2	Room	-	65	-	ns
	^L OFF		Full	-	-	89	-
Break-before-make time delay	t _D	DG9426E only, V _{NO} , V _{NC} = 1.5 V R _L = 300 Ω , C _L = 35 pF	Room	5			
Charge injection ^e	Q _{INJ}	$V_g=0~V,~R_g=0~\Omega,~C_L=1~nF$	Room	-	15	-	рС
Off isolation ^e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	-	-56	-	dB
Channel-to-channel crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-80	-	uБ
Source off capacitance ^e	C _{NO(off)}		Room	-	53	-	
Source on capacitance -	C _{NC(off)}	f = 1 MHz	nuuili	-	55	-	~~ ~
Drain off capacitance ^e	C _{COM(off)}	t = 1 MHz	Room	I	42	-	pF
Channel on capacitance ^e	C _{COM(on)}		Room	-	92	-	

Notes

a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test

b. Room = 25 °C, Full = As determined by the operating temperature suffix

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

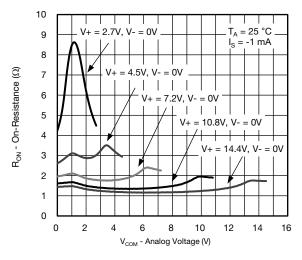
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet

e. Guaranteed by design, not subject to production test

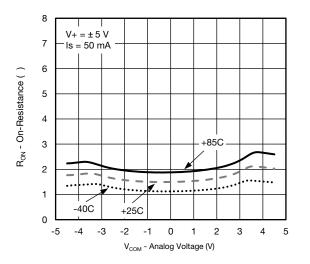
f. V_{IN} = Input voltage to perform proper function



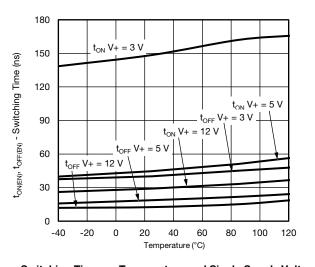
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



 R_{ON} vs. V_{COM} and Supply Voltage



R_{ON} vs. Analog Voltage and Temperature

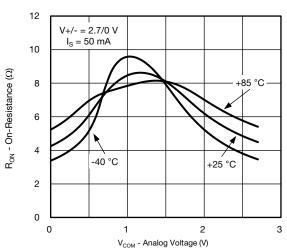


Switching Time vs. Temperature and Single Supply Voltage

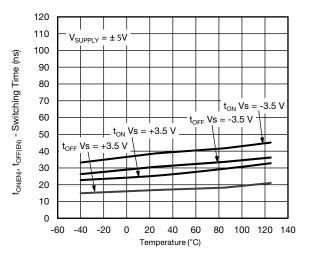
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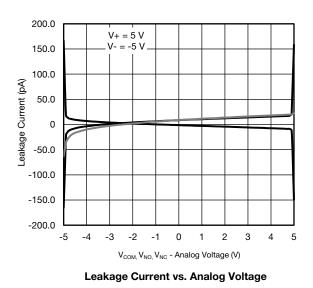
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R_{ON} vs. Analog Voltage and Temperature



Switching Time vs. Temperature and Dual Supply Voltage

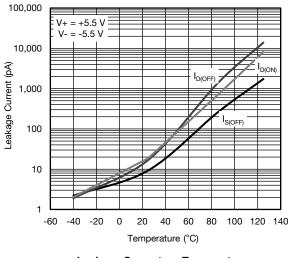




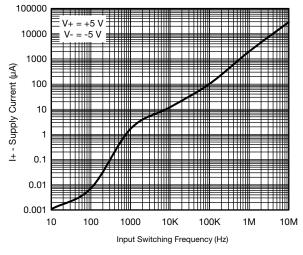
DG9424E, DG9425E, DG9426E

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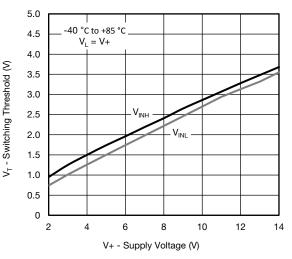
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



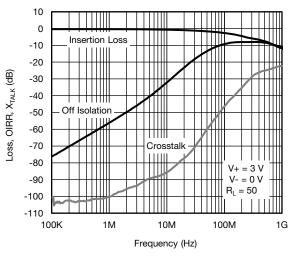
Leakage Current vs. Temperature



Switching Current vs. Input Switching Frequency



Switching Threshold vs. Supply Voltage



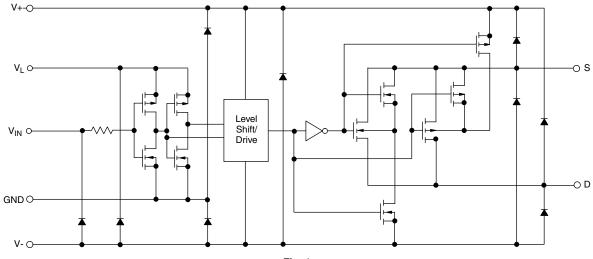
Insertion Loss, Off Isolation and Crosstalk vs. Frequency



DG9424E, DG9425E, DG9426E

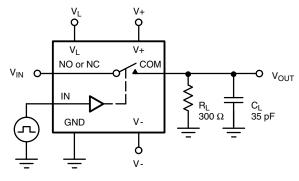
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SCHEMATIC DIAGRAM (typical channel)



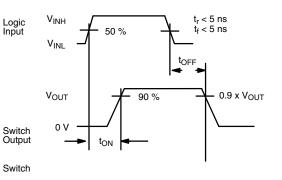


TEST CIRCUITS

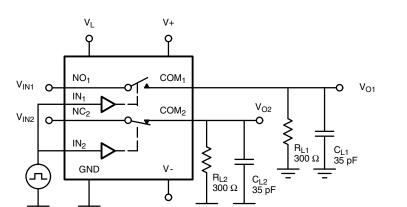


CL (includes fixture and stray capacitance)

 R_L $V_{OUT} = V_{IN}$ R_L + r_{ON}



Note: Logic input waveform is inverted for switches that have the opposite logic sense control



CL (includes fixture and stray capacitance)

v-

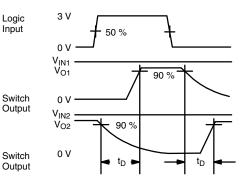


Fig. 3 - Break-Before-Make (DG9426E) 9

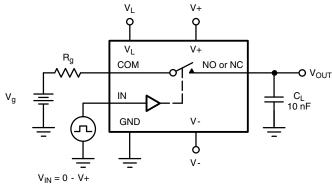
Fig. 2 - Switching Time

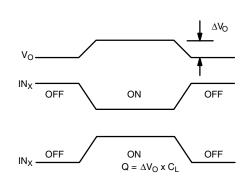
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TEST CIRCUITS





 $\ensuremath{\text{IN}_{\text{X}}}$ dependent on switch configuration Input polarity determined by sense of switch.

Fig. 4 - Charge Injection

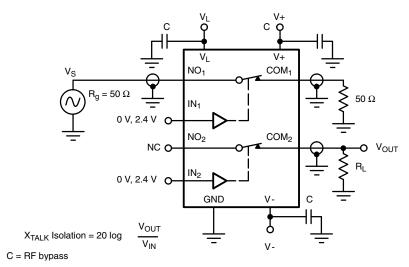
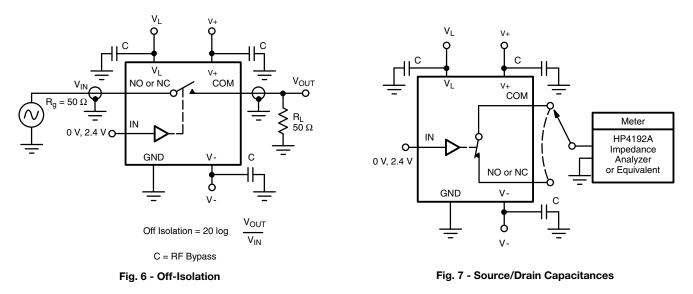


Fig. 5 - Crosstalk

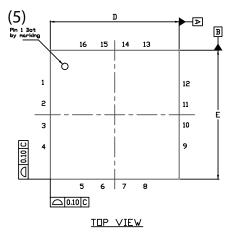


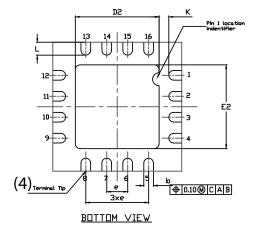
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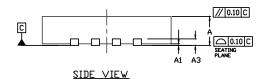
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QFN 4x4-16L Case Outline







VARIATION 1 VARIATION 2 MILLIMETERS(1) MILLIMETERS(1) DIM INCHES INCHES MIN. NOM. MAX. MIN. NOM. MAX. MIN. NOM. MAX. MIN. NOM. MAX. 0.75 0.85 0.95 0.029 0.033 0.037 0.75 0.85 0.95 0.029 0.033 0.037 А 0 -0.05 0 0.002 0 0.05 _ 0.002 A1 -_ 0 A3 0.20 ref. 0.008 ref. 0.20 ref. 0.008 ref. b 0.25 0.30 0.35 0.010 0.012 0.014 0.25 0.30 0.35 0.010 0.012 0.014 4.00 BSC D 0.157 BSC 4.00 BSC 0.157 BSC 0.087 0.106 2.1 2.2 0.083 2.6 2.7 0.102 D2 2.0 0.079 2.5 0.098 0.65 BSC 0.026 BSC 0.65 BSC 0.026 BSC е Е 4.00 BSC 0.157 BSC 4.00 BSC 0.157 BSC 0.087 2.1 2.2 0.083 2.7 0.102 0.106 2.6 E2 2.0 0.079 2.5 0.098 0.20 min. 0.008 min 0.20 min. 0.008 min. Κ 0.5 0.7 0.020 0.024 0.028 0.5 0.016 0.020 L 0.6 0.3 0.4 0.012 N⁽³⁾ 16 16 16 16 Nd⁽³⁾ 4 4 4 4 Ne⁽³⁾ 4 4 4 4

Notes

⁽¹⁾ Use millimeters as the primary measurement.

⁽²⁾ Dimensioning and tolerances conform to ASME Y14.5M. - 1994.

⁽³⁾ N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.

⁽⁴⁾ Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.

⁽⁵⁾ The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.

⁽⁶⁾ Package warpage max. 0.05 mm.

ECN: S13-0893-Rev. B, 22-Apr-13 DWG: 5890

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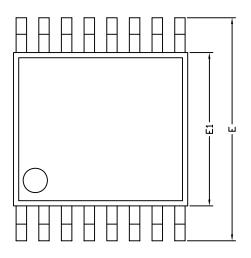
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Package Information

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TSSOP: 16-LEAD





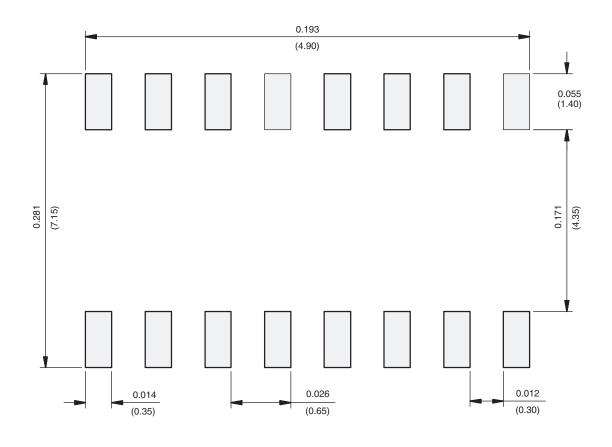
	C	DIMENSIONS IN MILLIMETERS					
Symbols	Min	Nom	Мах				
A	-	1.10	1.20				
A1	0.05	0.10	0.15				
A2	-	1.00	1.05				
В	0.22	0.28	0.38				
С	-	0.127	-				
D	4.90	5.00	5.10				
E	6.10	6.40	6.70				
E1	4.30	4.40	4.50				
е	-	0.65	-				
L	0.50	0.60	0.70				
L1	0.90	1.00	1.10				
у	-	-	0.10				
θ1	0°	3°	6°				
ECN: S-61920-Rev. D, 23 DWG: 5624	-Oct-06						



PAD Pattern

Vishay Siliconix

RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



Vishay

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